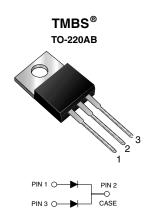


Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 20 A				
V_{RRM}	100 V				
I _{FSM}	250 A				
Typical V_F at $I_F = 20 A$ at $T_J = 125 °C$	0.63 V				
T _J max.	150 °C				

TYPICAL APPLICATIONS

For use in high frequency converters, high efficiency SMPS, output rectification, freewheeling, reverse battery protection, dc-to-dc system and increased power density systems.

FEATURES

• 150 °C high performance Schottky diode



· Very low forward voltage drop



Optimized V_F vs. I_R trade off for high efficiency

RoHS

- Increased ruggedness for reverse avalanche capability
- Negligible switching losses
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability

rating

Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Marking: V40100K Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	V40100K	UNIT			
Maximum repetitive peak reverse voltage	V _{RRM}	100	V			
Maximum average forward rectified current (fig. 1) per device per diode	I _{F(AV)}	40 20	Α			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	250	А			
Non-repetitive avalanche energy at $T_J = 25$ °C, $I_{AS} = 1.5$ A, L = 60 mH per diode	E _{AS}	67.5	mJ			
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode	I _{RRM}	1.0	А			
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs			
Operating junction and storage temperature range	T _J , T _{STG}	- 40 to + 150	°C			

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage ⁽²⁾	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 (minimum)	-	V
	I _R = 10 mA			105 (minimum)	-	
Instantaneous forward voltage per diode ⁽¹⁾	$I_F = 5 A$ $I_F = 10 A$ $I_F = 20 A$	T _A = 25 °C	V _F	0.51 0.59 0.72	- - 0.82	. v
	I _F = 5 A I _F = 10 A I _F = 20 A	T _A = 125 °C		0.44 0.53 0.63	- - 0.67	
Reverse current at rated V _R per diode ⁽²⁾	V _R = 70 V	T _A = 25 °C T _A = 125 °C	I _R	9 10	-	μA mA
	V _R = 100 V	T _A = 25 °C T _A = 125 °C		- 21	1000 45	μA mA

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL V40100K		UNIT
Maximum junction to case	per diode per device	$R_{ hetaJC}$	4 2	°C/W
Typical thermal resistance ca	se to heatsink	R_{\thetaCS}	0.5	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V40100K-E3/4W	1.85	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

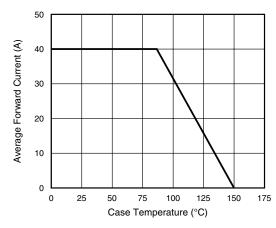


Figure 1. Forward Current Derating Curve

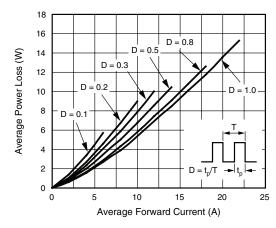


Figure 2. Forward Power Loss Characteristics Per Diode



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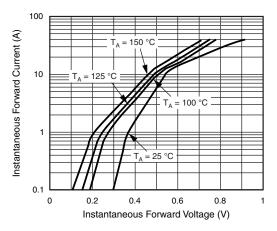


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

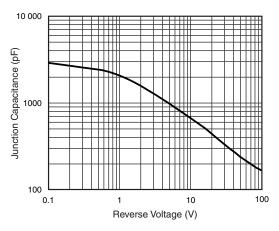


Figure 5. Typical Junction Capacitance Per Diode

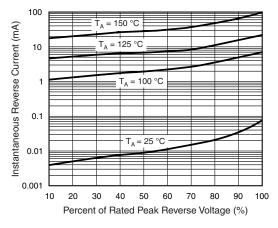


Figure 4. Typical Reverse Characteristics Per Diode

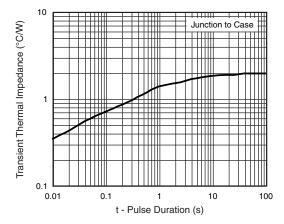
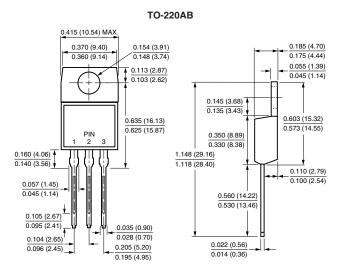


Figure 6. Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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